

BC214LB_L34Z Information



For Reference Only

Part Number BC214LB_L34Z

Manufacturer Fairchild/ON Semiconductor

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single

Description TRANS PNP 30V 0.5A TO-92 **Package** TO-226-3, TO-92-3 (TO-226AA)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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BC214LB_L34Z Specifications

Manufacturer Part NumberBC214LB_L34ZManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypePNPCurrent - Collector (Ic) (Max)500mAVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, Ic600mV @ 5mA, 100mACurrent - Collector Cutoff (Max)15nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce140 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3		
Category Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single TO-226-3, TO-92-3 (TO-226AA) Series - Transistor Type PNP Current - Collector (Ic) (Max) Voltage - Collector Emitter Breakdown (Max) Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Manufacturer Part Number	BC214LB_L34Z
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Package TO-226-3, TO-92-3 (TO-226AA) Series - Transistor Type PNP Current - Collector (Ic) (Max) 500mA Voltage - Collector Emitter Breakdown (Max) 30V Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) 15nA (ICBO) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition 200MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Category	Discrete Semiconductor Products
Series - Transistor Type PNP Current - Collector (Ic) (Max) 500mA Voltage - Collector Emitter Breakdown (Max) 30V Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) 15nA (ICBO) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition 200MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3		Transistors - Bipolar (BJT) - Single
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Current - Collector (Ic) (Max) Voltage - Collector Emitter Breakdown (Max) Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Series	-
Voltage - Collector Emitter Breakdown (Max) Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) 15nA (ICBO) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition 200MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Transistor Type	PNP
Vce Saturation (Max) @ Ib, Ic600mV @ 5mA, 100mACurrent - Collector Cutoff (Max)15nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce140 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Current - Collector (Ic) (Max)	500mA
Current - Collector Cutoff (Max) DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V Power - Max 625mW Frequency - Transition Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Voltage - Collector Emitter Breakdown (Max)	30V
DC Current Gain (hFE) (Min) @ Ic, Vce 140 @ 2mA, 5V 625mW Frequency - Transition 200MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package	Vce Saturation (Max) @ Ib, Ic	600mV @ 5mA, 100mA
Power - Max Frequency - Transition Operating Temperature Operating Type Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	Current - Collector Cutoff (Max)	15nA (ICBO)
Frequency - Transition 200MHz Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	DC Current Gain (hFE) (Min) @ Ic, Vce	140 @ 2mA, 5V
Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	Power - Max	625mW
Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	Frequency - Transition	200MHz
Package / Case TO-226-3, TO-92-3 (TO-226AA) Supplier Device Package TO-92-3	Operating Temperature	-55°C ~ 150°C (TJ)
Supplier Device Package TO-92-3	Mounting Type	Through Hole
	Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Report errors?	Supplier Device Package	TO-92-3
		Report errors?

BC214LB_L34Z Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BC214LB_L34Z Payment Methods



















BC214LB_L34Z Shipping Methods













If you have any question about BC214LB_L34Z, please do not hesitate to contact us!

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